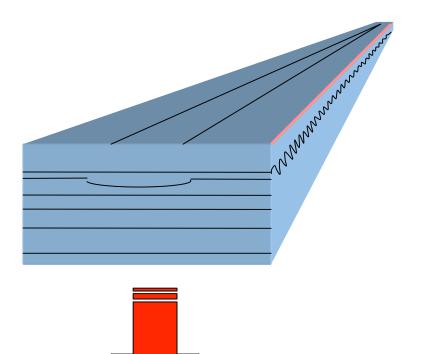
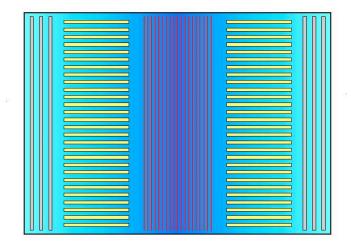




High Power Grating-Outcoupled Surface-Emitting Lasers Lasers









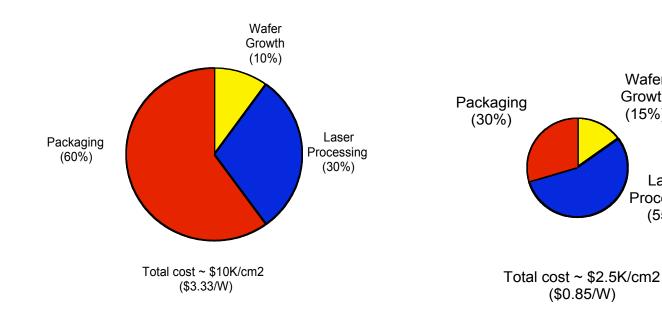
Advantages of GSE Lasers

- No optical facet damage
- Low-divergence output beam
- Power scaling by length
- High brightness
- Narrow, temperature-stable spectral envelope
- Wafer-level optical coatings
- Pretest in wafer form (short pulse)
- Visually prescreen defects through window
- Low-cost packaging
- Low-cost collimation optics
- Flexible beam aspect ratio





Low Cost Pump Solution Monolithic GSE Rack and Stack



Wafer Growth

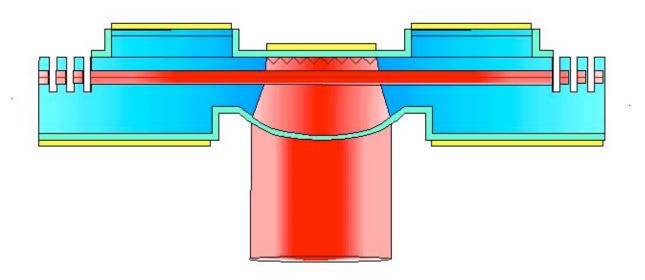
(15%)

Laser Processing (55%)





High Power Single Aperture GSE



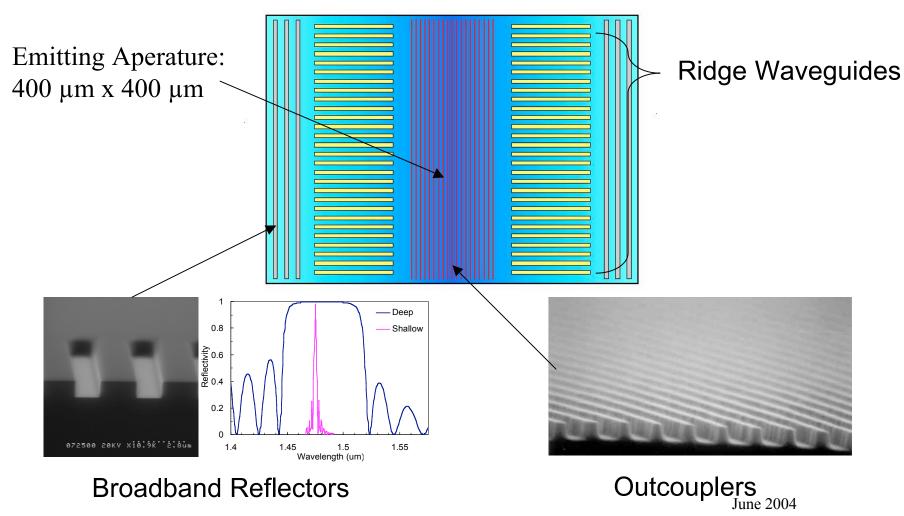
Air Force Program Goals:

- High Power (>5W) Surface Emitting Laser
- Operating Wavelength: 1550 nm





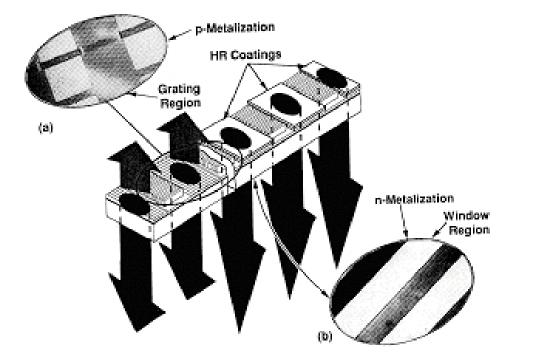
High Power Array







High Power Multi-Aperture GSEs



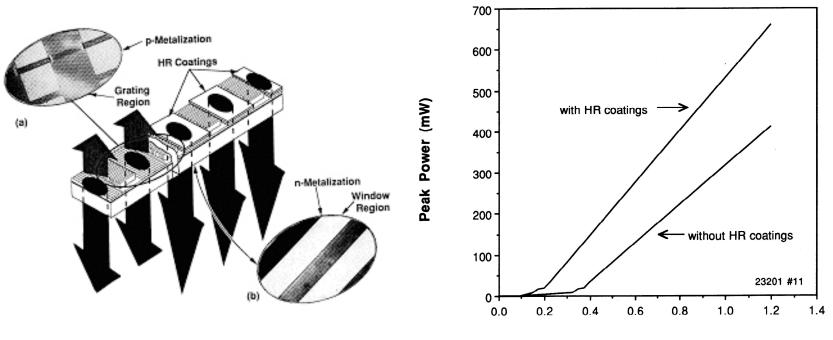
Pioneering work performed at RCA Laboratories (now Sarnoff Corp.) during the Phase Integrated Laser Optical Technology program (1985 - 1992)

10x4 GSE laser array





Substrate Emission with Reflector



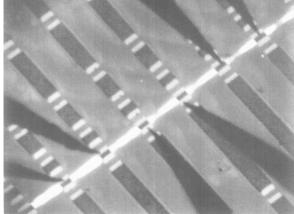
Current (A/pad)

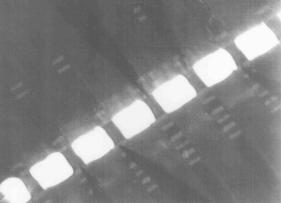


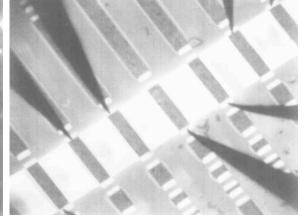




40 µm to 500 µm wide GSE Arrays



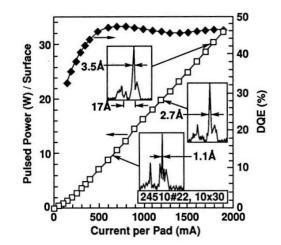


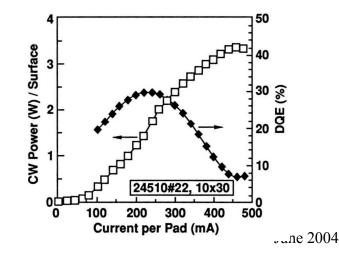


10-element-wide GSE array;

50-element-wide GSE array

125-element-wide GSE array.





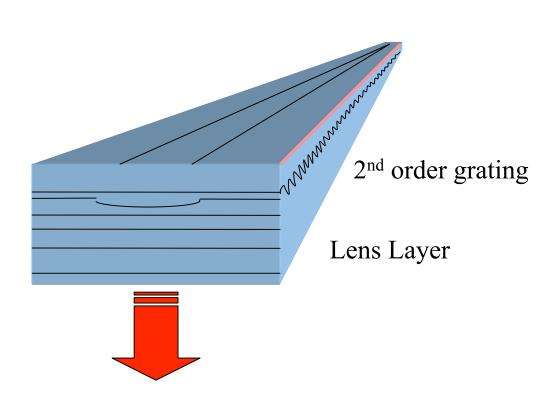




Lens-Like GSE Laser

Air Force Program

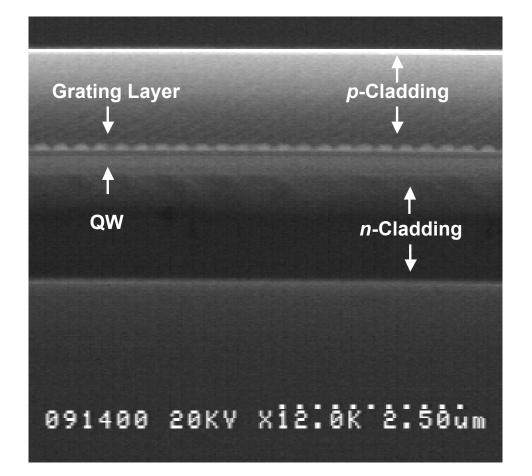
- High Brightness
- Surface Emission
- Single Frequency
- 975 nm
- •10 W DBR Stacks







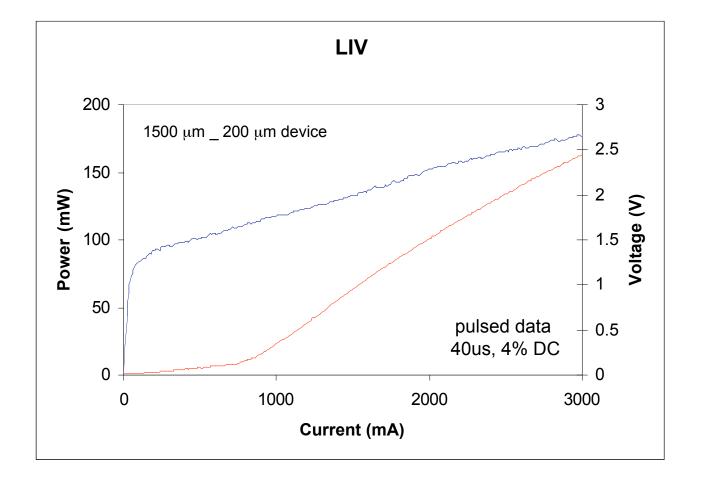
SEM of Regrown 2nd Order Gratings







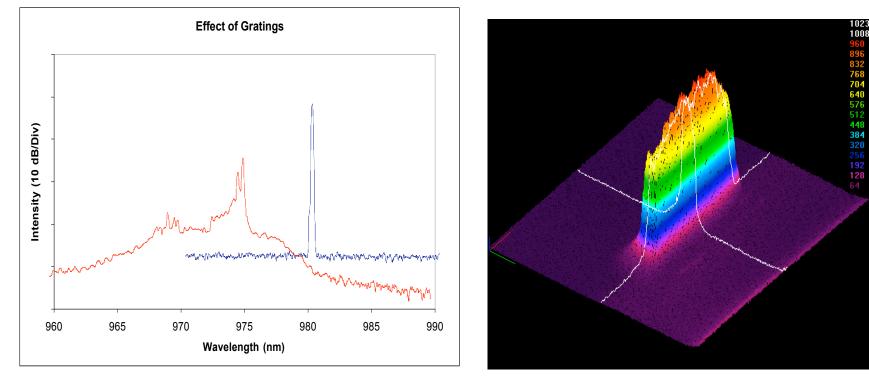
LLGSE LIV







LLGSE Spectrum and Near Field

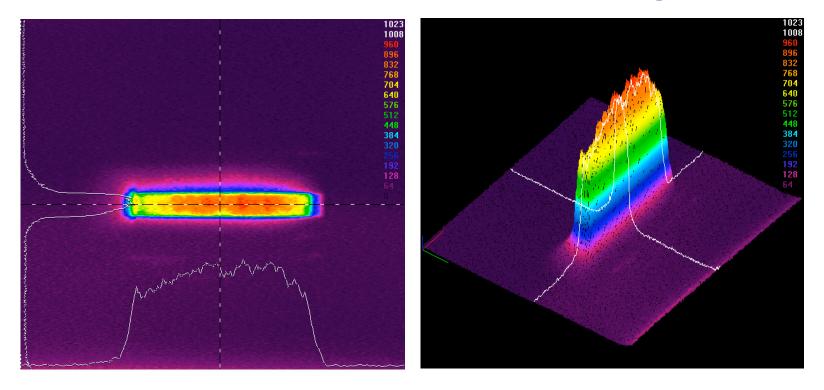


Air Force Research Laboratory's Directed Energy Directorate Contract F29601-98-C-0063





LLGSE Near Field Images



Near field images of spontaneous emission captured below threshold

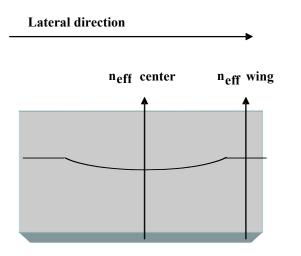


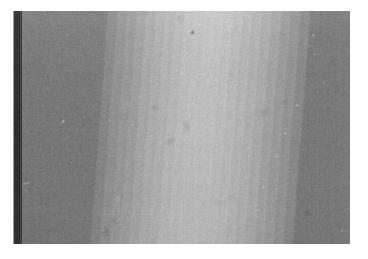


LLGSE Lens Channel

Optimize coupling with grating (κ L) for efficient surface emission

Integrate Lens-like layer for further mode stability





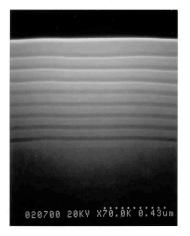




LLGSE Reflector Stack

Integrate distributed Bragg reflector (DBR) stack for

higher output power

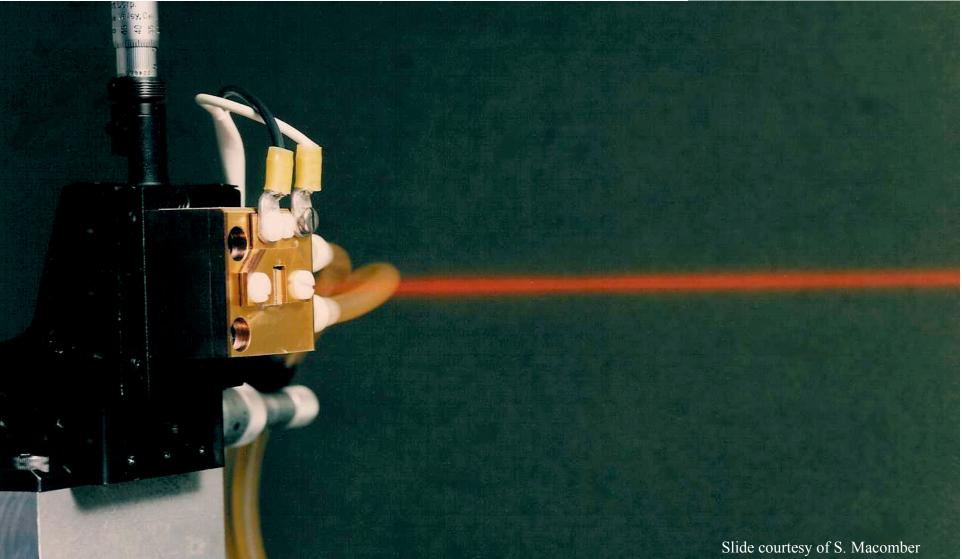


Scale device dimension to hit target power





Low-divergence Output Beam







Comparison of Source Brightness

Device	Parameters	Radiance	Beam Quality
Single wide-stripe edge emitter	2 W, 8° FWHM, 140 μ m stripe width	10 MW/cm ² -sr	23 × 1
Lensed bar	40 W, 1 cm, 8° FWHM 2×diff. limit fast axis	1.5	1,700 × 2
GSE Bar	30 W, 250 μm × 9000 μm	30	10 × 10

Slide courtesy of S. Macomber